Charge Sharing

Dynamic circuits have nodes which <u>retain charge</u>. We must pay attention to how coupling capacitances between critical nodes can affect the <u>charge</u> stored on these nodes.

One set of coupling capacitances we need to worry about is C_{gs}, C_{gd}.



When channel is off, $C_{gs} = C_{gd} \approx 0$. When channel is (turned-on) in strong inversion, C_{gs} and/or C_{gd} are maximized (value varys depending on saturated or non-saturated device operation).

What is dynamic coupling?



What effects do we need to be worried about in dynamic structures?



Node *X* is precharged <u>low</u> when CLK = 1.

Node *Y* is also precharged <u>low</u> when CLK = 1.

When *CLK* $1 \rightarrow 0$, *X* is left <u>floating</u>. Node *Y* will be pulled from $0 \rightarrow 1$.

Because device M1 is <u>on</u>, coupling capacitances C_{gd} , C_{gs} are maximized.

As node *Y* pulled $0 \rightarrow 1$, some charge will coupled from *Y* and *X*. This will reduce device M1's available V_{SG}, consequently <u>slowing</u> the rise time of *Y*. Will this cause problems???

Dynamic D Flip-Flop Falling Edge Triggered



Charge coupling problem – will cause *Y* to rise more slowly than it should.

If it rises slowly, what happens?

M2/M3 get turned on at the same time, we see some charge getting dumped on \overline{Q} , causing a <u>glitch</u> on Q!



See SPICE curve . . .

(SPICE curve given in class)

How can we fix this glitch problem???

If we want *Y* to rise faster despite slow-down effects of capacitive coupling, can make M1, M4 devices wider!!

SPICE simulation shows that doubling the transistor widths reduces the glitch by almost 50%.

Can also swap positions of M1, M4 (see result in SPICE curve...)



(SPICE curve given in class)

Input Pin Capacitance Measurement



 $V_{70} = 0.7 \times V_{DD}, V_{30} = 0.3 \times V_{DD}$

For falling V_{in} , let switch A open and switch B close when $V_{in} = V_{70}$, then let switch B open and switch A close when $V_{in} = V_{30}$. Switch B operates <u>exactly</u> opposite of switch A.

Amount of charge ΔQ stored on C_{fixed} is

 $\Delta \mathbf{Q} = \mathbf{I} \times \Delta \mathbf{t}$ $V_b \times \mathbf{C}_{\text{fixed}} = \mathbf{I} \times \Delta \mathbf{t}$

At Cpin we know

$$(V_{70} - V_{30}) \times C_{\text{pin}} = I \times \Delta t$$

$$V_b \times C_{\text{fixed}} = (V_{70} - V_{30}) \times C_{\text{pin}}$$
$$C_{\text{pin}} = \frac{V_b \times C_{\text{fixed}}}{V_{70} - V_{30}}$$
$$C_{\text{pin}} = \frac{V_b \times C_{\text{fixed}}}{0.4 \times V_{DD}}$$